

Document downloaded from:

<http://hdl.handle.net/10251/183166>

This paper must be cited as:

Ruiz-Castro, JE.; Acal, C.; Aguilera, AM.; Aguilera-Morillo, MC.; Roldán, JB. (2021). Linear-Phase-Type probability modelling of functional PCA with applications to resistive memories. *Mathematics and Computers in Simulation*. 186:71-79.  
<https://doi.org/10.1016/j.matcom.2020.07.006>



The final publication is available at

<https://doi.org/10.1016/j.matcom.2020.07.006>

Copyright Elsevier

Additional Information

## Abstract

Functional principal component analysis (FPCA) based on Karhunen-Loève (K-L) expansion allows to describe the stochastic evolution of the main characteristics associated to multiple systems and devices. Identifying the probability distribution of the principal component scores is fundamental to characterize the whole process. The aim of this work is to consider a family of statistical distributions that could be accurately adjusted to a previous transformation. Then, a new class of distributions, the linear-phase-type, is introduced to model the principal components. This class is studied in detail in order to prove, through the K-L expansion, that certain linear transformations of the process at each time point are phase-type distributed. This way, the one-dimensional distributions of the process are in the same linear-phase-type class. Finally, an application to model the reset process associated with resistive memories is developed and explained.

# 1 Introduction

Among the electron devices with greater potential in the current microelectronic industry landscape are Resistive Random Access Memories (RRAMs). The number of indexed publications in this field has skyrocketed and therefore, the attention of the academic community as well as the electronics companies' development teams is fixed on them. The applications of these new devices range from non-volatile memory circuits, security modules for cryptography and neuromorphic computation [10].

The stochastic nature of the physical mechanisms behind RRAM resistive switching (RS) operation makes the statistical modelling of the inherent device stochasticity essential. The key issue here rests upon the need to correctly explain variability in the current/voltage curves associated with long series of successive RS cycles [3, 11, 13, 1], i.e., cycles of continuous reset and set processes. If the device charge conduction is filamentary, the most common case, RS cycles get translated into rupture and rejuvenation of conductive filaments that dramatically changes the device resistance [7]. The modelling of the current versus voltage curves in these devices is of most importance for circuit design. Therefore, in this context, and taking into consideration that the experimental data we have are curves, an approach based on functional data analysis (FDA) can be applied in order to accurately model resistive memory characteristics.

A deep description of the main FDA methods with applications in different fields was developed in [12]. Functional principal component analysis (FPCA) based on Karhunen-Loève (K-L) expansion provides an orthogonal representation of an stochastic process in terms of uncorrelated random variables, called principal components (p.c.'s). The K-L expansion can be truncated so that the process is approximated in terms of the most explicative p.c.'s [2]. A three step algorithm for estimating FPCA from the reset curves (current versus voltage curves) of a sample of RRAM cycles was proposed in [3]. This new type of modelling can be very attractive from the circuit simulation viewpoint because it allows to describe the main characteristics of these devices, such as variabil-

ity. Making use of this technique, the implementation of variability in compact models for RRAMs can be greatly simplified.

Nevertheless, identifying the probability distribution of the principal components is fundamental to characterize the whole process through the K-L expansion. In previous studies, several authors have considered different transformations and used them as a starting point, they have fitted different distributions successfully. However, to find the appropriate transformation and its probability distribution is not an easy task. The aim of this work is to consider a family of statistical distributions that could be accurately adjusted for any transformation. In this respect, a new methodology is developed by considering phase-type distributions (PH) that were applied in [1, 11] for modelling the reliability functions associated to RRAM reset points, among others parameters. This class of distributions have been also considered in other multiple science fields such as queueing theory and reliability ([16], [14], [15]). The properties of this distribution class are very interesting and allow to achieve results in a well structured form. The developments and results can be expressed in an matrix-algorithmic and computational way. One of the main advantages of this class is that any non-negative distribution can be approximated as needed through a PH distribution [9]. In order to fit this distribution, the p.c.'s scores should be transformed previously to positive values. In fact, in this research, it is proved that for several transformations, the fit obtained is more accurate by considering PH distributions than any other distribution. A new class of distributions are introduced, the linear-phase-type distributions (LPH) defined as variables for which there is a linear transformation that is PH distributed. This class is studied in detail in order to prove, through K-L expansion, that certain linear transformations of the process at each time point is PH distributed too.

In addition to this introduction, the paper has three other sections. The new LPH distributions and their main properties are studied in detail in Section 2. Then, the one-dimensional LPH distributions of the process are obtained from the LPH distributions of the p.c.'s through the K-L expansion. Finally, the proposed methodology is applied on different samples of current/voltage curves associated to RRAM devices in Section 4.

## 2 LPH modelling

In reliability, computer and electronic engineering, physics, queues theory and other fields, multiple probability distributions are frequently used, including the exponential, Erlang and Weibull distributions. Most of them involve calculations that may become unmanageable, due to the analytic expressions required. PH play an important role in this respect. This type of distributions enables us to express the main results in an algorithmic and computational way. This class of

distribution was described in detail in [9].

## 2.1 PH distributions

**Definition 1** A nonnegative random variable  $X$  is a PH distribution if its reliability function is given by

$$R(x) = P\{X > x\} = \boldsymbol{\alpha} e^{\mathbf{T}x} \mathbf{e} \quad ; \quad x \geq 0,$$

where  $\boldsymbol{\alpha}$  is a substochastic vector of order  $m$ ,  $\mathbf{T}$  a subgenerator of order  $m$  (matrix  $m \times m$  where all diagonal elements are negative, all off-diagonal elements are non-negative, invertible and all row sums are non-positive) and, throughout the paper,  $\mathbf{e}$  is a column vector of ones with appropriate order.

A PH distribution can be defined as the time up to the absorption in an absorbent Markov chain with initial distribution and generator for the transient states  $\boldsymbol{\alpha}$  and  $\mathbf{T}$ , respectively. In this case,  $(\boldsymbol{\alpha}, \mathbf{T})$  is called the representation of the PH distribution.

Multiple good properties of these distributions are described in [9]. One of the main properties is that of PH distributions can approximate arbitrarily closely any probability distribution defined on the nonnegative real line.

## 2.2 LPH distributions

A new probability distribution class is defined in this subsection. This class is called the linear-phase-type distribution class (LPH). A LPH distribution is defined as follows.

**Definition 2** A random variable  $X$  follows a LPH distribution if  $Y = a + bX$  is PH distributed for  $a$  and  $b$  ( $b \neq 0$ ) in  $\mathbb{R}$ .

If the representation of  $Y$  is  $(\boldsymbol{\alpha}, \mathbf{T})$  then the reliability function of  $X$  (LPH) is

$$R_X(x) = P(X > x) = \begin{cases} \boldsymbol{\beta} e^{\mathbf{S}x} \mathbf{e} & ; \text{ for } x > \frac{-a}{b}; b > 0 \\ 1 - \boldsymbol{\beta} e^{\mathbf{S}x} \mathbf{e} & ; \text{ for } x < \frac{-a}{b}; b < 0 \end{cases},$$

where  $\boldsymbol{\beta} = \boldsymbol{\alpha} e^{\mathbf{T}a}$ ,  $\mathbf{S} = b\mathbf{T}$  and  $\mathbf{e}$  is a column vector with appropriate order. In this case, will we denote the 4-tuple  $(a, b, \boldsymbol{\beta}, \mathbf{S})$  as the representation of the corresponding LPH.

The density function of this class of distributions is given by

$$f_X(x) = \begin{cases} -\boldsymbol{\beta} e^{\mathbf{S}x} \mathbf{S}^0 & ; \text{ for } x > \frac{-a}{b}; b > 0 \\ \boldsymbol{\beta} e^{\mathbf{S}x} \mathbf{S}^0 & ; \text{ for } x < \frac{-a}{b}; b < 0 \end{cases},$$



$$W_2(t) = F_1 * F_2(t) = \int_0^\infty F_1(du) F_2(t-u) du.$$

It is well-known that the Laplace-Stieltjes transform of the convolution is the product of the Laplace-Stieltjes transforms and that there is a biunivocal relationship between the original distribution and its Laplace-Transform.

Given the distribution function of a PH distribution with representation  $(\boldsymbol{\alpha}_i, \mathbf{T}_i)$ , then its Laplace-Stieltjes transform is given by

$$F_i^*(s) = \boldsymbol{\alpha}_i(s\mathbf{I} - \mathbf{T}_i)^{-1}\mathbf{T}_i^0.$$

Then,

$$\begin{aligned} W_2^*(s) &= \boldsymbol{\rho}_2(s\mathbf{I} - \mathbf{L}_2)^{-1}\mathbf{L}_2^0 = (\boldsymbol{\alpha}_1, \mathbf{0}) \begin{pmatrix} s\mathbf{I} - \mathbf{T}_1 & \mathbf{T}_1^0 \otimes \boldsymbol{\alpha}_2 \\ \mathbf{0} & s\mathbf{I} - \mathbf{T}_2 \end{pmatrix}^{-1} \begin{pmatrix} \mathbf{0} \\ \mathbf{T}_2^0 \end{pmatrix} \\ &= (\boldsymbol{\alpha}_1, \mathbf{0}) \begin{pmatrix} (s\mathbf{I} - \mathbf{T}_1)^{-1} & (s\mathbf{I} - \mathbf{T}_1)^{-1}\mathbf{T}_1^0\boldsymbol{\alpha}_2(s\mathbf{I} - \mathbf{T}_2)^{-1} \\ \mathbf{0} & (s\mathbf{I} - \mathbf{T}_2)^{-1} \end{pmatrix} \begin{pmatrix} \mathbf{0} \\ \mathbf{T}_2^0 \end{pmatrix} \\ &= \boldsymbol{\alpha}_1(s\mathbf{I} - \mathbf{T}_1)^{-1}\mathbf{T}_1^0 \cdot \boldsymbol{\alpha}_2(s\mathbf{I} - \mathbf{T}_2)^{-1}\mathbf{T}_2^0 = F_1^*(s) \cdot F_2^*(s). \end{aligned}$$

We assume that  $W_{n-1} = \sum_{i=1}^{n-1} Y_i$  is PH-distributed with representation  $(\boldsymbol{\rho}_{n-1}, \mathbf{L}_{n-1})$ . Given that  $W_n = W_{n-1} + Y_n$  and  $\boldsymbol{\rho}_n = (\boldsymbol{\rho}_{n-1}, \mathbf{0})$  and  $\mathbf{L}_n = \begin{pmatrix} \mathbf{L}_{n-1} & \mathbf{L}_{n-1}^0 \\ \mathbf{0} & \mathbf{T}_n^0 \end{pmatrix}$ , then

$$\begin{aligned} W_n^*(s) &= \boldsymbol{\rho}_n(s\mathbf{I} - \mathbf{L}_n)^{-1}\mathbf{L}_n^0 = \\ &= \boldsymbol{\rho}_{n-1}(s\mathbf{I} - \mathbf{L}_{n-1})^{-1}\mathbf{L}_{n-1}^0 \cdot \boldsymbol{\alpha}_n(s\mathbf{I} - \mathbf{T}_n)^{-1}\mathbf{T}_n^0 = W_{n-1}^*(s) \cdot F_n^*(s). \end{aligned}$$

### Corollary 1

Let  $\{X_i; i = 1, \dots, n\}$  be a finite sequence of independent LPH distributions with PH-distributions associated given by  $\{Y_i = a_i + bX_i; i = 1, \dots, n\}$  with representation  $(\boldsymbol{\alpha}_i, \mathbf{T}_i)$  for  $i=1, \dots, n$ . Then, the variable  $\Lambda_n = \sum_{i=1}^n X_i$  is LPH distributed with representation  $\left( \sum_{i=1}^n a_i, b, \boldsymbol{\rho}_n e^{\mathbf{L}_n \sum_{i=1}^n a_i}, b\mathbf{L}_n \right)$ .

*Proof.*

From result 1,  $\sum_{i=1}^n Y_i = b\Lambda_n + \sum_{i=1}^n a_i$  is PH with representation  $(\boldsymbol{\rho}_n, \mathbf{L}_n)$ . Then,

$$\Lambda_n = \frac{1}{b} \sum_{i=1}^n Y_i - \frac{1}{b} \sum_{i=1}^n a_i \text{ is LPH with representation } \left( \sum_{i=1}^n a_i, b, \boldsymbol{\rho}_n e^{\mathbf{L}_n \sum_{i=1}^n a_i}, b\mathbf{L}_n \right).$$

Next, we show that a positive homothecy of a PH distribution is also PH distributed.

**Result 2**

Let  $Y$  be a PH distribution with representation  $(\boldsymbol{\alpha}, \mathbf{T})$  then the variable  $\gamma Y$  is PH distributed with representation  $(\boldsymbol{\alpha}, \frac{1}{\gamma} \mathbf{T})$ , being  $\gamma$  a non-negative real number.

The proof of this result is immediate. Thus,

$$P(\gamma Y > t) = P(Y > t/\gamma) = \boldsymbol{\alpha} e^{\frac{1}{\gamma} \mathbf{T} t} \mathbf{e} \quad ; \quad t > 0.$$

**Corollary 2**

Let  $X$  be a LPH distribution with representation  $(a, b, \boldsymbol{\beta}, \mathbf{S})$ , then the variable  $\gamma X$  is LPH with representation  $(|\gamma| a, b \cdot \text{sgn}(\gamma), \boldsymbol{\beta}, \frac{1}{\gamma} \mathbf{S})$ , being  $\gamma$  a non-zero real number,  $|\cdot|$  the absolute value function and  $\text{sgn}(\cdot)$  the sign function.

*Proof.*

If  $X$  is a LPH distribution with representation  $(a, b, \boldsymbol{\beta}, \mathbf{S})$ , then there exist  $a$  and  $b$  such that  $Y = a + bX$  is PH $(\boldsymbol{\alpha}, \mathbf{T})$  where  $\boldsymbol{\beta} = \boldsymbol{\alpha} e^{\mathbf{T} a}$  and  $\mathbf{S} = b \mathbf{T}$ .

Then, from *Result 2* we have that any homothecy of a LPH distribution is also LPH distributed.

- If  $\gamma > 0$ ,  $\gamma Y = \gamma a + b \gamma X$  is PH $(\boldsymbol{\alpha}, \frac{1}{\gamma} \mathbf{T})$ .

Then,

$$\gamma X \text{ is LPH with representation } \left( \gamma a, b, \boldsymbol{\alpha} e^{\mathbf{T} a}, \frac{b}{\gamma} \mathbf{T} \right) \equiv \left( \gamma a, b, \boldsymbol{\beta}, \frac{1}{\gamma} \mathbf{S} \right).$$

- If  $\gamma < 0$ ,  $-\gamma Y = -\gamma a - b(\gamma X)$  is PH $(\boldsymbol{\alpha}, \frac{-1}{\gamma} \mathbf{T})$ .

Then,

$$\gamma X \text{ is LPH with representation } \left( -\gamma a, -b, \boldsymbol{\alpha} e^{\mathbf{T} a}, \frac{b}{\gamma} \mathbf{T} \right) \equiv \left( -\gamma a, -b, \boldsymbol{\beta}, \frac{1}{\gamma} \mathbf{S} \right).$$

Therefore  $\gamma X$  is LPH distributed with representation  $(|\gamma| a, b \cdot \text{sgn}(\gamma), \boldsymbol{\beta}, \frac{1}{\gamma} \mathbf{S})$ .

**Result 3 (Density of the LPH class)**

The set of LPH distributions is dense in the set of probability distributions defined on any half-line of real numbers.

*Proof.*

This theorem is proved from the classical result for PH distributions: the set of PH distributions is dense in the set of probability distributions on the non-negative half-line. Let  $W$  be a random variable defined on  $w > c$  for any real

number  $c$ . It is immediate that  $W - c$  is defined on the nonnegative half-line. Then, there exists a variable  $Y$ , PH distributed, so closed as desirable to  $W - c$ . Therefore, the variable  $X = Y + c$ , which is LPH, approximates to the initial variable  $W$ .

A similar reasoning can be done for the case when  $W$  is defined on  $w < c$  for any real number  $c$ . In this case  $-W + c$  is defined on  $\mathbb{R}^+$ . Then, there exists a variable  $Y$ , PH distributed, so closed as desirable to  $-W + c$ . For this case, the variable  $X = -Y + c$ , which is LPH, approximates the initial variable  $W$ .

### 3 LPH modelling of functional PCA

Let  $X$  be a functional variable whose observed values are curves, and let us assume that  $X = \{X(t) : t \in T\}$  is a second order stochastic process, continuous in quadratic mean, whose sample functions belong to the Hilbert space  $L^2(T)$  of square integrable functions with the usual inner product  $\langle f, g \rangle = \int_T f(t)g(t)dt, \forall f, g \in L^2(T)$ .

In order to reduce the infinite dimension of a functional variable and to explain its dependence structure by a reduced set of uncorrelated variables, multivariate PCA was extended to the functional case [6]. The functional principal components (p.c.'s) are obtained as uncorrelated generalized linear combinations of the process variables with maximum variance (Var). Then, the  $j$ -th p.c. score is given by  $\xi_j = \int_T (X(t) - \mu(t)) f_j(t) dt$ , where the weight function or loading  $f_j$  is the value of the argument  $f(t)$  that maximizes de objective function with the corresponding constraints

$$\begin{cases} \text{Var} \left[ \int_T (X(t) - \mu(t)) f(t) dt \right] \\ \text{subject to } \|f\|^2 = 1 \text{ and } \int f_\ell(t) f(t) dt = 0, \ell = 1, \dots, j-1. \end{cases}$$

It can be shown that the weight functions are the eigenfunctions of the covariance operator  $C$ . That is, the solutions to the eigenequation  $C(f_j)(t) = \int C(t, s) f_j(s) ds = \lambda_j f_j(t)$ , where  $C(t, s)$  is the covariance function and  $\lambda_j = \text{Var}[\xi_j]$ . Then, the process admits the following orthogonal representation (K-L expansion):

$$X(t) = \mu(t) + \sum_{j=1}^{\infty} \xi_j f_j(t),$$

with  $\mu(t)$  being the mean function. This principal component decomposition can be truncated providing the best linear approximation of the sample curves in the least squares sense  $X^q(t) = \mu(t) + \sum_{j=1}^q \xi_j f_j(t)$ , whose explained variance is given by  $\sum_{j=1}^q \lambda_j$ .

There are three main groups of rules for choosing the number of principal components.



if  $f_j(t) > 0$  then  $f_j(t) \xi_j$  is LPH with representation  $\left(f_j(t) a_j, b, \beta_j, \frac{1}{f_j(t)} \mathbf{S}_j\right)$ ,  
if  $f_j(t) < 0$  then  $f_j(t) \xi_j$  is LPH with representation  $\left(-f_j(t) a_j, b, \beta_j, \frac{-1}{f_j(t)} \mathbf{S}_j\right)$ .  
Then, from Corollary 1,  $\sum_{j=1}^q \xi_j f_j(t)$  is also LPH.

## 4 Application

The devices employed in this paper are composed of a metal-oxide-semiconductor stack whose metal electrode used was copper (200 nm thick), a dielectric 10 nm thick ( $\text{HfO}_2$ ) and a bottom electrode made of  $/\text{Si-}n^+$ . The resistive memories were fabricated and measured at the Institute of Microelectronics of Barcelona (CNM-CSIC). The variability of these devices is generated by an inherent stochastic process that changes extremely the inner resistance of the device by means of resistive switching physical mechanisms. The experimental data consist of a sample of current-voltage curves corresponding to the reset-set cycles associated with the formation and rupture of a conductive filament that shorts the electrodes and changes drastically the device resistance. From the mathematical viewpoint, the main objective here is to determine the current probability distribution at each voltage in the reset process by means of the K-L expansion and the LPH distributions previously introduced.

In this study, we have 232 reset curves denoted by  $\{I_i(v) : v \in [0, V_{i-\text{reset}}], i = 1, \dots, 232\}$  with  $V_{i-\text{reset}}$  being the reset voltage. Before applying FPCA to characterize the whole process through the K-L expansion, we must carry out some important previous steps proposed in [3]. Briefly, this approach consists in synchronising all curves in the same interval due to the reset voltage is different for each curve, and using P-spline smoothing to reconstruct all reset curves since we only have discrete observations at a finite set of current values until the voltage reset for each curve. In this paper, the initial domain was transformed in the interval  $[0,1]$  and a cubic B-Spline basis of dimension 20 with 17 equally spaced knots and penalty parameter  $\lambda = 0.5$  was considered. Figure 1 shows all the smoothed registered curves in the interval  $[0,1]$ , denoted by  $\{I_i^*(u) : u \in [0,1], i = 1, \dots, n\}$ , and the estimation of the mean function (red line).

Then, FPCA is estimated and the percentages of variance explained by the first four p.c.'s are 99.42, 0.44, 0.08 and 0.04, respectively. Let us observe that only the first p.c. explains more than 99% of the total variability of the process. Hence, by considering the K-L expansion, principal component decomposition of the registered reset curves can be truncated in the first term as follows:  $I^{*1}(u) = \bar{I}^*(u) + \xi_1^* f_1^*(u)$ ,  $u \in [0,1]$ . This approach can be used for circuit simulation in

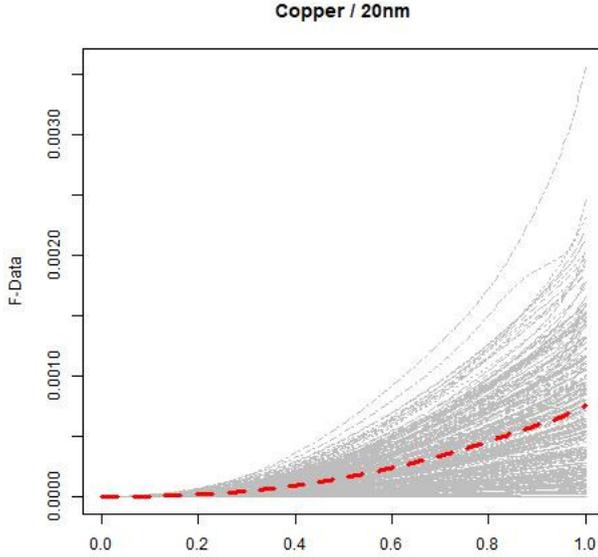


Figure 1: Sample group mean function (dashed red line) and all the P-spline smoothed registered curves.

Distribution	p-value K-S	p-value Anderson-Darling	LogL
PHD	0.11	0.054	18.11
Weibull	0.004	0.004	0.78
Normal	0.02	0.006	7.79
Cauchy	< 0.001	< 0.001	-42.30

Table 1: Comparison among all distributions is considered. P-values of the Kolmogorov-Smirnov and Anderson-Darling tests, and the value of the maximum log-likelihood are showed for each distribution.

this type of devices. Nevertheless, the probability distribution of the first p.c. is unknown.

In order to fit a probability model to the scores of the first p.c. different distributions were employed but none of them could be accepted (p-value associated with Kolmogorov-Smirnov test was  $< 0.01$  in all of them). Then, some transformation is necessary. In this study, the LPH distributions associated with the linear transformation  $1 + 1000 \times \xi_1^*$  is considered. The p.c. is multiplied by 1000 because the standard variation of the principal component is very small, with minimum and maximum values of the component equal to  $3.2e^{-04}$  and  $7e^{-04}$ , respectively. These facts produce a great number of phases in the corresponding PH distribution estimated (more than 1000 produced exploding effects). After that, all values were in  $[-1, 1]$  and then 1 is added (to consider a PH distribution). Although the constant and slope values could be calculated by maximum likelihood (we are working on it), in this paper they were found *ad hoc*, taking into account that PHD are non-negative variables (the values of the first p.c. are positives and negatives).

The EM algorithm was used for estimating the parameters of a PHD with  $m$  transient stages and any internal structure for matrix  $\mathbf{T}$  ([4][5]). This methodology has also been applied to estimate the parameters of the PH distributions embedded in the study of the variability in resistive memories. The algorithm is described in [1]. The optimum value was reached for 21 stages. Besides, in order to prove that PHD is better than any other distribution, Weibull, Normal and Cauchy distributions were fitted as well. Their estimation by maximum likelihood are  $W(\beta = 4.4344, \lambda = 1.0897)$ ,  $N(\mu = 0.9958, \sigma = 0.234)$  and  $C(\gamma = 0.9252, \delta = 0.1505)$ , respectively. The results provided by all of them are given and compared in Table 1. Thus, taking into account the logL value and the p-values of the K-S and the Anderson-Darling tests, the best distribution to get an accurate fit of the first p.c. score is the PH distribution. In fact, at 5% significance level, only the PH distribution can be accepted to model the first p.c. score according to the p-values provided by the Kolmogorov-Smirnov and Anderson-Darling tests. This conclusion can be achieved graphically. The cumulative hazard rate (topleft), the density function (topright), the cumulative distribution function (bottomleft) and the reliability function (bottomright) of data with the fitting by means of PH, Weibull, Normal and Cauchy distributions are displayed in Figure 2. In order to sum up, we have proved that the considered linear transformation of the first p.c. is PH distributed with representation  $(\boldsymbol{\alpha}, \mathbf{T})$ . Therefore, the first p.c. score can be modelled through a LPH distribution with representation  $(1, 1000, \boldsymbol{\beta}, \mathbf{S})$ . Finally, the reset process  $I^{*1}(u)$  is LPH distributed as well with representation

$$\left( |f_1^*(u)| - 1000\bar{I}^*(u) \operatorname{sgn}(f_1^*(u)), 1000 \operatorname{sgn}(f_1^*(u)), \boldsymbol{\alpha} e^{\mathbf{T} \left( 1 - \frac{1000}{f_1^*(u)} \bar{I}^*(u) \right)}, \frac{1000}{f_1^*(u)} \mathbf{T} \right).$$

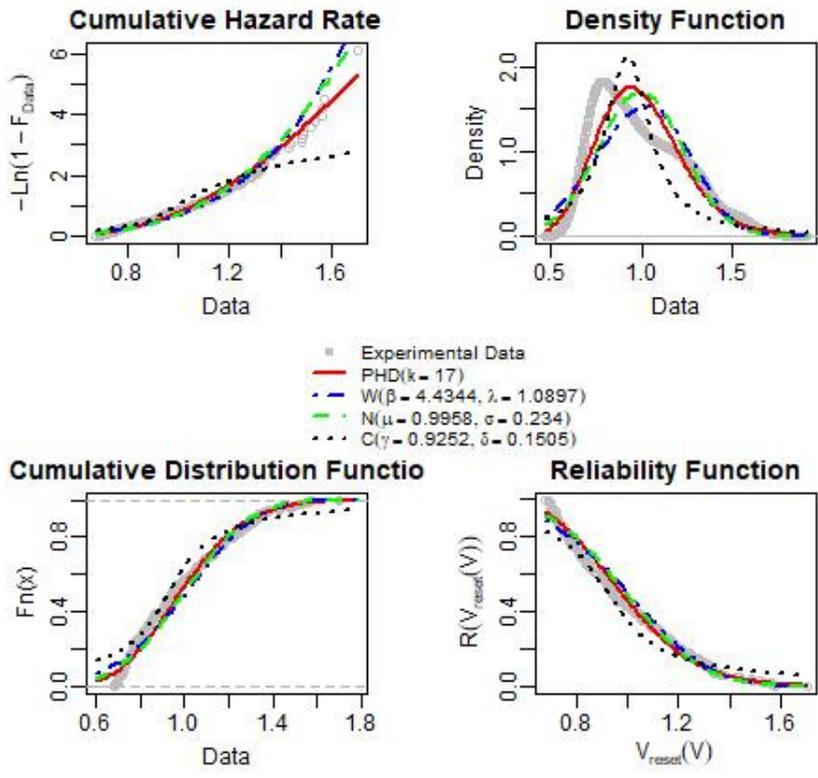


Figure 2: The cumulative hazard rate (topleft), the density function (topright), the cumulative distribution function (bottomleft) and the reliability function (bottomright) of experimental data with the fitting by means of PH, Weibull, Normal and Cauchy distributions.

## 5 Conclusions

A new probability distribution class with good properties, the LPH class, has been introduced to model the principal components in a matrix and algorithmic form. Multiple properties of this distribution class are developed, including that the LPH class is dense in the probability distribution class defined on any half-line of real numbers. Functional principal components analysis provides a representation of a stochastic process through uncorrelated random variables called principal components. It is of great interest identifying the probability distribution of these components to analyse the random behaviour of the process. In this work, it has also been proved that the process, characterized through the K-L expansion, follows a LPH distribution at each point. The results have been applied to model the stochastic behaviour of resistive memories. In this case, one principal component is considered and the explicit representation of the LPH is given for the stochastic process at each point.

## References

- [1] C. Acal, J. E. Ruiz-Castro, A.M. Aguilera, F. Jiménez-Molinos, and J.B. Roldán. Phase-type distributions for studying variability in resistive memories. *Journal of Computational and Applied Mathematics*, 345(1):23–32, 2019.
- [2] A. M. Aguilera and M. C. Aguilera-Morillo. Penalized PCA approaches for B-spline expansions of smooth functional data. *Applied Mathematics and Computation*, 219(14):7805–7819, 2013.
- [3] M. C. Aguilera-Morillo, A.M. Aguilera, F. Jiménez-Molinos, and J.B. Roldán. Stochastic modeling of random access memories reset transitions. *Mathematics and Computers in Simulation*, 159(1):197–209, 2019.
- [4] S. Asmussen. *Ruin probabilities*. World Scientific, 2000.
- [5] P. Buchholz, J. Kriege, and I. Felko. *Input modeling with phase-type distributions and Markov models, Theory and Applications*. Springer, 2014.
- [6] J. C. Deville. Méthodes statistiques et numériques de l’analyse harmonique. *Annales de l’INSEE*, 15:3–101, 1974.
- [7] G. González-Cordero, M.B. González, H. García, F. Campabadal, S. Dueñas, H. Castán, F. Jiménez-Molinos, and J.B. Roldán. A physically based model for resistive memories including a detailed temperature and variability description. *Microelectronic Engineering*, 178(1):26–29, 2017.

- [8] I.T. Joliffe. *Principal Component Analysis*. Springer in Statistics. Springer, New York., 2002.
- [9] M.F. Neuts. *Matrix geometric solutions in stochastic models. An algorithmic approach, in Probability Distributions of Phase Type*. Baltimore: John Hopkins University Press, 1981.
- [10] F Pan, S Gao, C Chen, C Song, and F Zeng. Recent progress in resistive random access memories: materials, switching mechanisms and performance. *Materials Science and Engineering*, 83:1–59, 2014.
- [11] E. Pérez, D. Maldonado, C. Acal, J. E. Ruiz-Castro, F. J. Alonso, A. M. Aguilera, F. Jiménez-Molinos, C. Wenger, and J. B. Roldán. Analysis of the statistics of device-to-device and cycle-to-cycle variability in tin/ti/al:hfo2/tin rrams. *Microelectronics Engineering*, 214(1):104–109, 2019.
- [12] J. O. Ramsay and B. W. Silverman. *Functional data analysis (Second Edition)*. Springer-Verlag, 2005.
- [13] J.B. Roldán, F.J. Alonso, A.M. Aguilera, D. Maldonado, and M. Lanza. Time series statistical analysis: a powerful tool to evaluate the variability of resistive switching memories. *Journal of Applied Physics*, 125(1):174504, 2019.
- [14] J. E. Ruiz-Castro. A complex multi-state  $k$ -out-of- $n$ :  $g$  system with preventive maintenance and loss of units. *Reliability Engineering & System Safety*, 197(106797):1–18, 2020.
- [15] J. E. Ruiz-Castro and M. Dawabsha. A multi-state warm standby system with preventive maintenance, loss of units and an indeterminate multiple number of repairpersons. *Computers & Industrial Engineering*, 142(106348):1–16, 2020.
- [16] J. E. Ruiz-Castro, M. Dawabsha, and F. J. Alonso. Discrete-time markovian arrival processes to model multi-state complex systems with loss of units and an indeterminate variable number of repairpersons. *Reliability Engineering & System Safety*, 174(1):114–127, 2018.